

# N-Channel Enhancement Mode Power MOSFET

#### Description

The RM2310 uses advanced trench technology to provide excellent  $R_{DS(ON)}$ , low gate charge and operation with gate voltages as low as 2.5V. This device is suitable for use as a Battery protection or in other switching application.

## **General Features**

• V<sub>DS</sub> =60V,I<sub>D</sub> =3A

 $R_{DS(ON)}$  <105m $\Omega$  @ V<sub>GS</sub>=10V

- $R_{DS(ON)} < 125m\Omega @ V_{GS}=4.5V$
- High power and current handing capability
- Lead free product is acquired
- Surface mount package

#### Application

- Battery switch
- DC/DC converter
- Halogen-free

#### Package Marking and Ordering Information

| Device Marking | Device | Device Package | Reel Size | Tape width | Quantity   |
|----------------|--------|----------------|-----------|------------|------------|
| 2310           | RM2310 | SOT-23-3L      | Ø180mm    | 8 mm       | 3000 units |

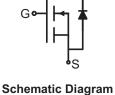
#### Absolute Maximum Ratings (T<sub>A</sub>=25°Cunless otherwise noted)

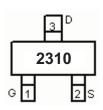
| Parameter  | Symbol          | Limit      | Unit |  |
|--|-----------------|------------|------|--|
| Drain-Source Voltage                             | Vds             | 60         | V    |  |
| Gate-Source Voltage                              | Vgs             | ±20        | V    |  |
| Drain Current-Continuous                         | I <sub>D</sub>  | 3          | А    |  |
| Drain Current-Pulsed (Note 1)                    | I <sub>DM</sub> | 10         | А    |  |
| Maximum Power Dissipation                        | PD              | 1.7        | W    |  |
| Operating Junction and Storage Temperature Range | TJ,TSTG         | -55 To 150 | °C   |  |

# Thermal Resistance, Junction-to-Ambient (Note 2)R<sub>0JA</sub>73.5°C/W

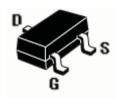
#### Electrical Characteristics (T<sub>A</sub>=25 $^{\circ}$ C unless otherwise noted)

| Parameter                       | Symbol            | Condition                                 | Min | Тур | Мах | Unit |
|---------------------------------|-------------------|---|-----|-----|-----|------|
| Off Characteristics             |                   |   |     |     |     |      |
| Drain-Source Breakdown Voltage  | BV <sub>DSS</sub> | V <sub>GS</sub> =0V Ι <sub>D</sub> =250μΑ | 60  | 65  | -   | V    |
| Zero Gate Voltage Drain Current | I <sub>DSS</sub>  | V <sub>DS</sub> =60V,V <sub>GS</sub> =0V  | -   | -   | 1   | μA   |





Marking and Pin Assignment



SOT-23 -3L Top View



**RM2310** 

| Gate-Body Leakage Current              | IGSS                     | $V_{GS}=\pm 20V, V_{DS}=0V$                             | -   | -    | ±100 | nA |  |
|--|--------------------------|---|-----|------|------|----|--|
| On Characteristics <sup>(Note 3)</sup> |                          |   |     |      |      |    |  |
| Gate Threshold Voltage                 | V <sub>GS(th)</sub>      | V <sub>DS</sub> =V <sub>GS</sub> ,I <sub>D</sub> =250µA | 1.0 | 1.2  | 1.9  | V  |  |
|  | ance R <sub>DS(ON)</sub> | V <sub>GS</sub> =10V, I <sub>D</sub> =3A                | -   | 78   | 105  | mΩ |  |
| Drain-Source On-State Resistance       |                          | V <sub>GS</sub> =4.5V, I <sub>D</sub> =3A               | -   | 95   | 125  | mΩ |  |
| Forward Transconductance               | <b>g</b> fs              | V <sub>DS</sub> =15V,I <sub>D</sub> =2A                 | 3   | -    | -    | S  |  |
| Dynamic Characteristics (Note4)        | ł                        |   | •   | •    |      | •  |  |
| Input Capacitance                      | C <sub>lss</sub>         |   | -   | 247  | -    | PF |  |
| Output Capacitance                     | Coss                     | V <sub>DS</sub> =30V,V <sub>GS</sub> =0V,<br>F=1.0MHz   | -   | 34   | -    | PF |  |
| Reverse Transfer Capacitance           | Crss                     |   | -   | 19.5 | -    | PF |  |
| Switching Characteristics (Note 4)     |                          |   |     |      |      |    |  |
| Turn-on Delay Time                     | t <sub>d(on)</sub>       |   | -   | 6    | -    | nS |  |
| Turn-on Rise Time                      | tr                       | V <sub>DD</sub> =30V,I <sub>D</sub> =1.5A               | -   | 15   | -    | nS |  |
| Turn-Off Delay Time                    | t <sub>d(off)</sub>      | $V_{GS}$ =10V, $R_{GEN}$ =1 $\Omega$                    | -   | 15   | -    | nS |  |
| Turn-Off Fall Time                     | t <sub>f</sub>           |   | -   | 10   | -    | nS |  |
| Total Gate Charge                      | Qg                       | )/0)///0A   | -   | 6    | -    | nC |  |
| Gate-Source Charge                     | Q <sub>gs</sub>          | $V_{DS}=30V,I_{D}=3A,$                                  | -   | 1    | -    | nC |  |
| Gate-Drain Charge                      | Q <sub>gd</sub>          | V <sub>GS</sub> =4.5V                                   | -   | 1.3  | -    | nC |  |
| Drain-Source Diode Characteristics     | ·                        |   |     | •    |      |    |  |
| Diode Forward Voltage (Note 3)         | V <sub>SD</sub>          | V <sub>GS</sub> =0V,I <sub>S</sub> =3A                  | -   | -    | 1.2  | V  |  |
| Diode Forward Current (Note 2)         | I <sub>S</sub>           |   | -   | -    | 3    | А  |  |

### Notes:

1. Repetitive Rating: Pulse width limited by maximum junction temperature.

**2.** Surface Mounted on FR4 Board,  $t \le 10$  sec. **3.** Pulse Test: Pulse Width  $\le 300\mu$ s, Duty Cycle  $\le 2\%$ .

4. Guaranteed by design, not subject to production

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# **RATING AND CHARACTERISTICS CURVES (RM2310)**

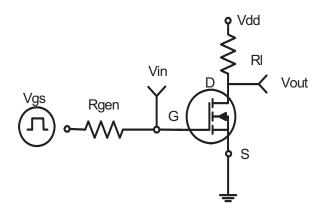
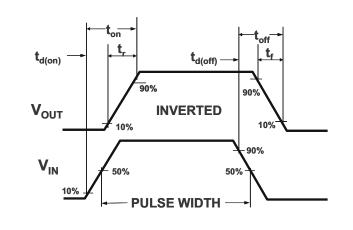
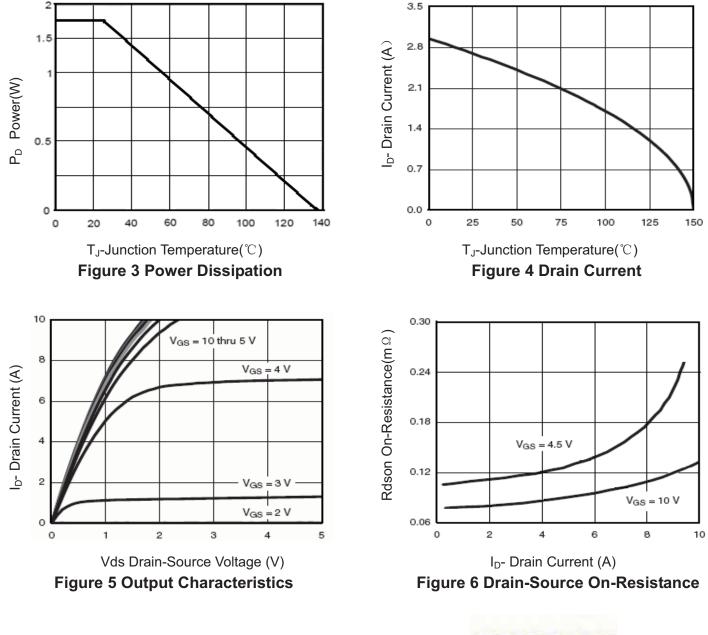


Figure 1:Switching Test Circuit

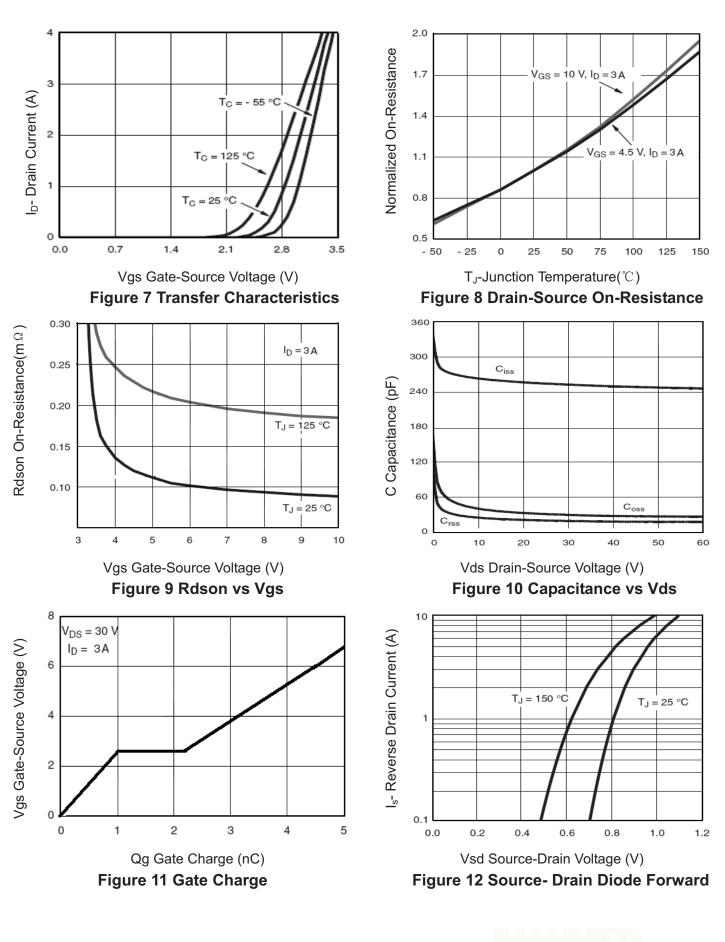






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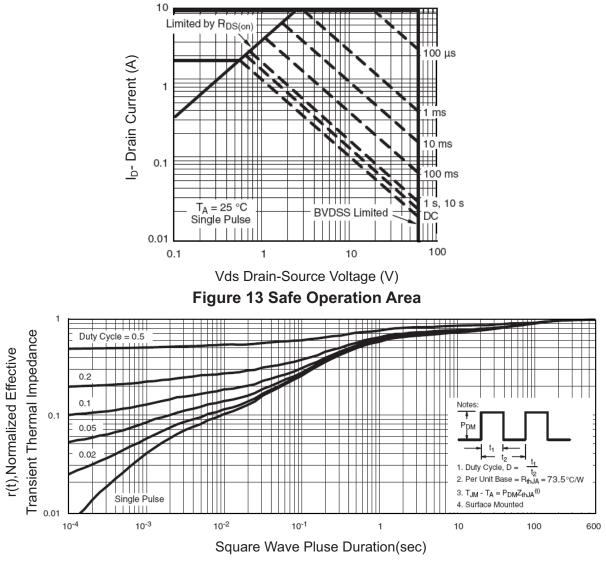
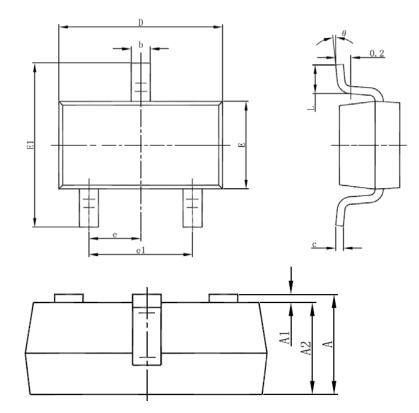


Figure 14 Normalized Maximum Transient Thermal Impedance



## SOT-23-3L Package Information



| Symbol | Dimensions Ir | n Millimeters | Dimensions In Inches |       |  |
|--------|---------------|---------------|----------------------|-------|--|
| Symbol | Min           | Max           | Min                  | Max   |  |
| A      | 1.050         | 1.250         | 0.041                | 0.049 |  |
| A1     | 0.000         | 0.100         | 0.000                | 0.004 |  |
| A2     | 1.050         | 1.150         | 0.041                | 0.045 |  |
| b      | 0.300         | 0.500         | 0.012                | 0.020 |  |
| с      | 0.100         | 0.200         | 0.004                | 0.008 |  |
| D      | 2.820         | 3.020         | 0.111                | 0.119 |  |
| E      | 1.500         | 1.700         | 0.059                | 0.067 |  |
| E1     | 2.650         | 2.950         | 0.104                | 0.116 |  |
| е      | 0.950(BSC)    |               | 0.037(BSC)           |       |  |
| e1     | 1.800         | 2.000         | 0.071                | 0.079 |  |
| L      | 0.300         | 0.600         | 0.012                | 0.024 |  |
| θ      | 0°            | 8°            | 0°                   | 8°    |  |

#### **Notes**

1. All dimensions are in millimeters.

2. Tolerance ±0.10mm (4 mil) unless otherwise specified

3. Package body sizes exclude mold flash and gate burrs. Mold flash at the non-lead sides should be less than 5 mils.

4. Dimension L is measured in gauge plane.

5. Controlling dimension is millimeter, converted inch dimensions are not necessarily exact.



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